

FJP19430TU Datasheet

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DiGi Electronics Part Number	FJP19430TU-DG
Manufacturer	onsemi
Manufacturer Product Number	FJP19430TU
Description	TRANS PNP 230V 15A TO220-3
Detailed Description	Bipolar (BJT) Transistor PNP 230 V 15 A 30MHz 80 W Through Hole TO-220-3



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Purchase and inquiry

Manufacturer Product Number:

FJP1943OTU

Series:

-

Transistor Type:

PNP

Voltage - Collector Emitter Breakdown (Max):

230 V

Current - Collector Cutoff (Max):

5 μ A (ICBO)

Power - Max:

80 W

Operating Temperature:

-50°C ~ 150°C (TJ)

Package / Case:

TO-220-3

Base Product Number:

FJP194

Manufacturer:

onsemi

Product Status:

Obsolete

Current - Collector (Ic) (Max):

15 A

Vce Saturation (Max) @ Ib, Ic:

3V @ 800mA, 8A

DC Current Gain (hFE) (Min) @ Ic, Vce:

80 @ 1A, 5V

Frequency - Transition:

30MHz

Mounting Type:

Through Hole

Supplier Device Package:

TO-220-3

Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

REACH Status:

REACH Unaffected

HTSUS:

8541.29.0075



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November 2008

FJP1943

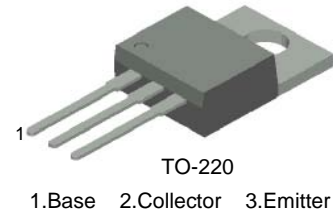
PNP Epitaxial Silicon Transistor

Applications

- High-Fidelity Audio Output Amplifier
- General Purpose Power Amplifier

Features

- High Current Capability: $I_C = -15A$.
- High Power Dissipation : 80watts.
- High Frequency : 30MHz.
- High Voltage : $V_{CEO} = -230V$
- Wide S.O.A for reliable operation.
- Excellent Gain Linearity for low THD.
- Complement to FJP5200
- Full thermal and electrical Spice models are available.
- Same transistor is also available in:
 - TO264 package, 2SA1943/FJL4215 : 150 watts
 - TO3P package, 2SA1962/FJA4213 : 130 watts
 - TO220F package, FJPF1943 : 50 watts



Absolute Maximum Ratings* $T_a = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
BV_{CBO}	Collector-Base Voltage	-230	V
BV_{CEO}	Collector-Emitter Voltage	-230	V
BV_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current	-15	A
I_B	Base Current	-1.5	A
P_D	Total Device Dissipation($T_C=25^\circ C$) Derate above $25^\circ C$	80 0.64	W W/ $^\circ C$
T_J, T_{STG}	Junction and Storage Temperature	- 50 ~ +150	$^\circ C$

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics* $T_a=25^\circ C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
$R_{\theta JC}$	Thermal Resistance, Junction to Case	1.25	$^\circ C/W$

* Device mounted on minimum pad size

h_{FE} Classification

Classification	R	O
h_{FE1}	55 ~ 110	80 ~ 160

Electrical Characteristics* $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	$I_C=-5\text{mA}, I_E=0$	-230			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C=-10\text{mA}, R_{BE}=\infty$	-230			V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_E=-5\text{mA}, I_C=0$	-5			V
I_{CBO}	Collector Cut-off Current	$V_{CB}=-230\text{V}, I_E=0$			-5.0	μA
I_{EBO}	Emitter Cut-off Current	$V_{EB}=-5\text{V}, I_C=0$			-5.0	μA
h_{FE1}	DC Current Gain	$V_{CE}=-5\text{V}, I_C=-1\text{A}$	55		160	
h_{FE2}	DC Current Gain	$V_{CE}=-5\text{V}, I_C=-7\text{A}$	35	60		
$V_{CE}(\text{sat})$	Collector-Emitter Saturation Voltage	$I_C=-8\text{A}, I_B=-0.8\text{A}$		-0.4	-3.0	V
$V_{BE}(\text{on})$	Base-Emitter On Voltage	$V_{CE}=-5\text{V}, I_C=-7\text{A}$		-1.0	-1.5	V
f_T	Current Gain Bandwidth Product	$V_{CE}=-5\text{V}, I_C=-1\text{A}$		30		MHz
C_{ob}	Output Capacitance	$V_{CB}=-10\text{V}, f=1\text{MHz}$		360		pF

* Pulse Test: Pulse Width=20 μs , Duty Cycles \leq 2%**Ordering Information**

Part Number	Marking	Package	Packing Method	Remarks
FJP1943RTU	J1943R	TO-220	TUBE	hFE1 R grade
FJP1943OTU	J1943O	TO-220	TUBE	hFE1 O grade

Typical Characteristics

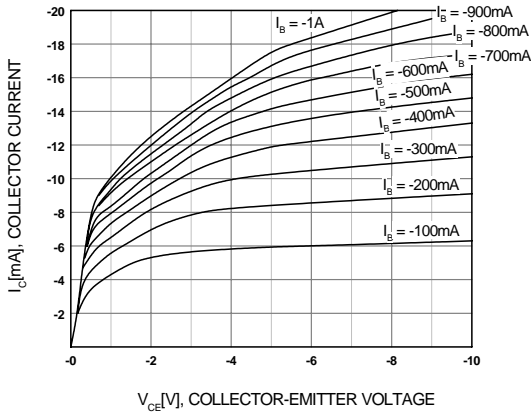


Figure 1. Static Characteristic

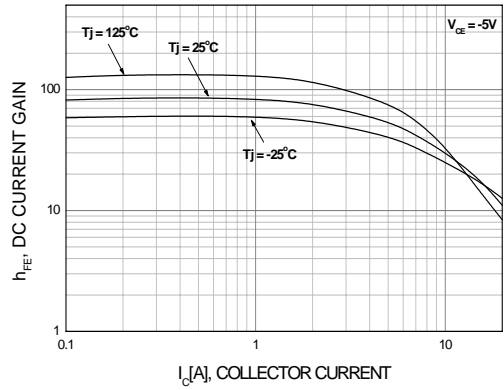


Figure 2. DC current Gain (R Grade)

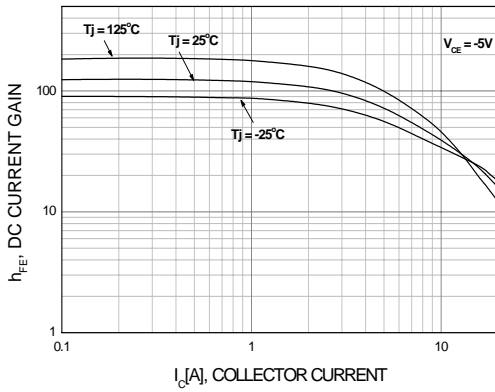


Figure 3. DC current Gain (O Grade)

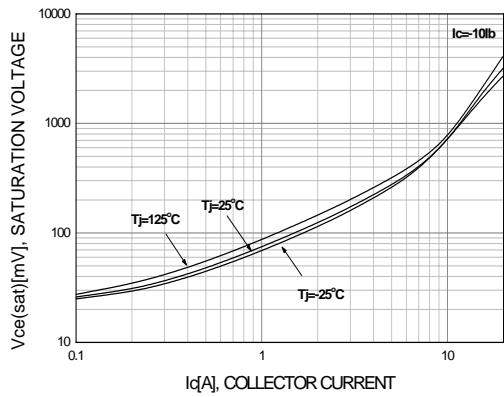


Figure 4. Collector-Emitter Saturation Voltage

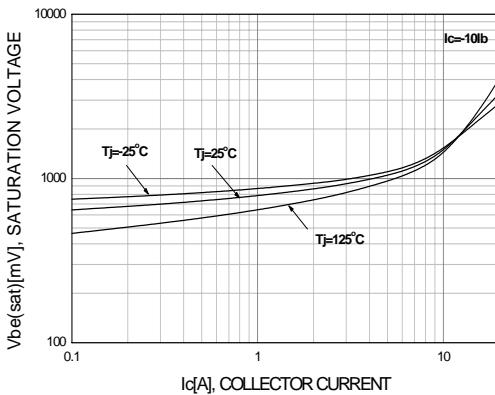


Figure 5. Base-Emitter Saturation Voltage

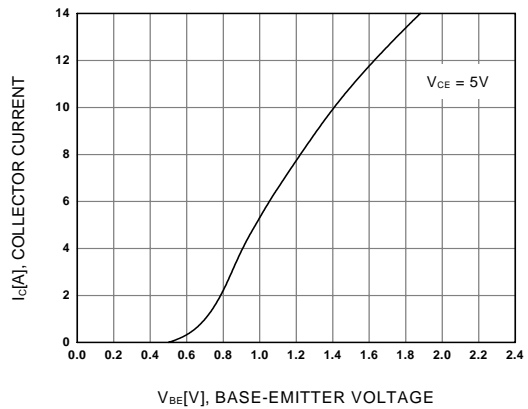


Figure 6. Base-Emitter On Voltage

Typical Characteristics

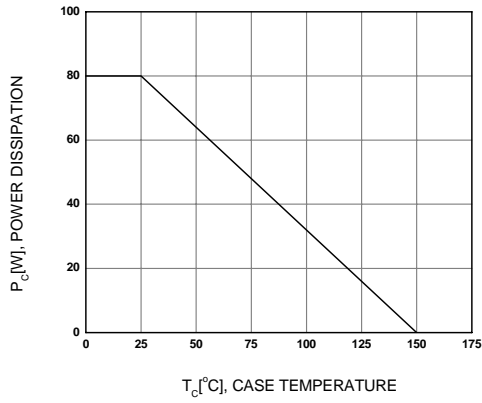


Figure 7. Power Derating

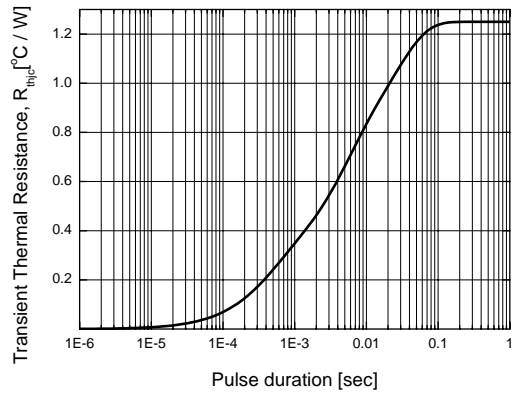



Figure 8. Thermal Resistance



- NOTES:
- A) REFERENCE JEDEC, TO-220, VARIATION AB
 - B) ALL DIMENSIONS ARE IN MILLIMETERS.
 - C) DIMENSIONS COMMON TO ALL PACKAGE SUPPLIERS EXCEPT WHERE NOTED [].
 - D) LOCATION OF MOLDED FEATURE MAY VARY (LOWER LEFT CORNER, LOWER CENTER AND CENTER OF THE PACKAGE)
 - E) DOES NOT COMPLY JEDEC STANDARD VALUE.
 - F) "A1" DIMENSIONS AS BELOW:
 SINGLE GAUGE = 0.51 - 0.61
 DUAL GAUGE = 1.10 - 1.45
 - G) DRAWING FILE NAME: TO220B03REV9
 - H) PRESENCE IS SUPPLIER DEPENDENT
 - I) SUPPLIER DEPENDENT MOLD LOCKING HOLES IN HEATSINK.

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